

### Features

- Maximum output current is 1.2A
- Range of operation input voltage: Max 15V
- Line regulation: 0.03%/V (typ.)
- Standby current: 2mA (typ.)
- Load regulation: 0.2%/A (typ.)
- Environment Temperature: -20°C~85°C

### Applications

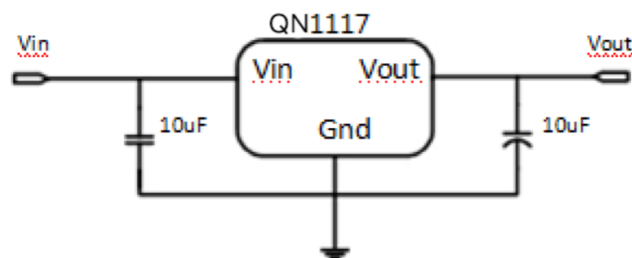
- Power Management for Computer Mother Board, Graphic Card
- LCD Monitor and LCD TV
- DVD Decode Board
- ADSL Modem
- Post Regulators For Switching Supplies

### General Description

QN1117 is a series of low dropout three-terminal regulators with a dropout of 1.3V at 800mA load current. QN1117 features a very low standby current 2mA compared to 5mA of competitor. Other than a fixed version,  $V_{out} = 1.2V, 1.8V, 2.5V, 2.85V, 3.3V,$  and 5V, QN1117 has an adjustable version, which can provide an output voltage from 1.25 to 12V with only

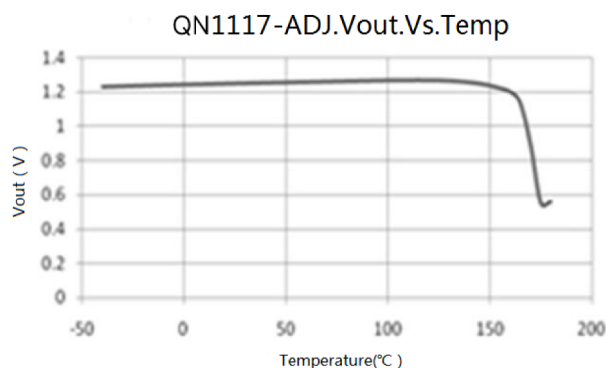
two external resistors. QN1117 offers thermal shut down function, to assure the stability of chip and power system. And it uses trimming technique to guarantee output voltage accuracy within 2%. Other output voltage accuracy can be customized on demand, such as 1%. QN1117 is available in SOT-223, TO-252 power package.

### Typical Application



Application circuit of QN1117 fixed version

### Typical Electrical Characteristic



### Selection Table

Marking	Part No.	Output Voltage	Package
1117 XX YYWW	XX=12	1.2V	SOT-223 TO-252
	XX=18	1.8V	
	XX=28	2.85V	
	XX=25	2.5V	
	XX=33	3.3V	
	XX=50	5.0V	
	XX=AD	Adj	

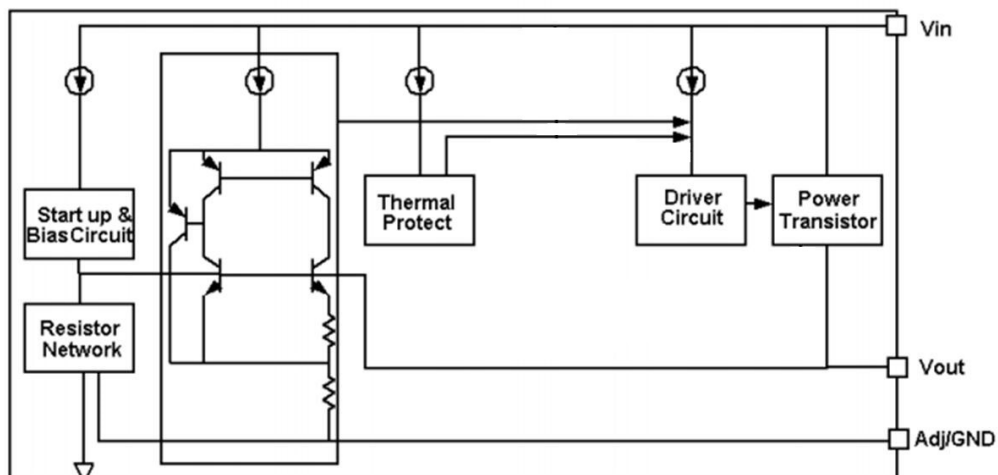
### Ordering Information

Marking	Designator	Description
1117 XX YYWW	1117 C	Product code
	XX	Output Voltage(1.2~12.0V)
	YYWW	DATE CODE

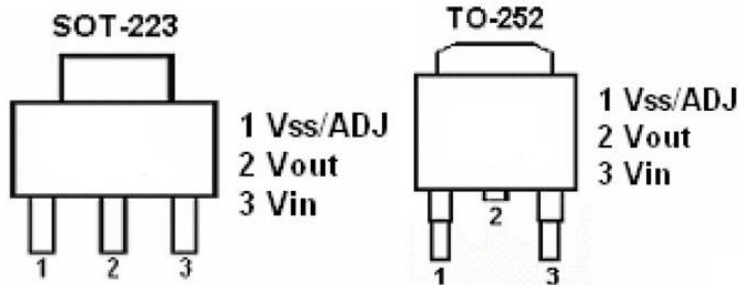
Note: "XX" stands for output voltages. Other voltages can be specially customized

Parameters	Description
Temperature & Rohs	C: -40~85°C , Pb Free Rohs Std.
Package type	L: SOT-223 O: TO-252
Packing type:	TR: Tape & Reel (Standard)
Voltage accuracy	2%(Customized)

### Block Diagram



### Pin Configuration



### Absolute Maximum Ratings

Max Input Voltage ..... 18V  
 Max Operating Junction Temperature(Tj) ..... 150°C  
 Ambient Temperature(Ta) ..... -40°C~ 85°C  
 Storage Temperature(Ts)..... -40°C~150°C  
 Lead Temperature & Time..... 260°C 10S  
 Caution: Exceed these limits to damage to the device. Exposure to absolute maximum rating conditions may affect device reliability.

### Recommended Work Conditions

Recommended maximum input voltage ..... 15V  
 Recommended operating junction temperature(Tj) ..... -20~125°C

### Thermal Information

Parameter	Package	Rating	Unit
Package thermal resistance	SOT-223	20	°C/W
	TO-252	12.5	°C/W



# QN1117

## 800mA Bipolar Linear Regulator

### Electrical Characteristics

T<sub>A</sub>=25°C, unless otherwise noted.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V <sub>ref</sub>	Reference voltage	QN1117-Adj 10mA ≤ I <sub>out</sub> ≤ 800mA, V <sub>in</sub> =3.25V	1.225	1.25	1.275	V
V <sub>out</sub>	Output voltage	QN1117-1.2V 0 ≤ I <sub>out</sub> ≤ 800mA, V <sub>in</sub> =3.2V	1.176	1.2	1.224	V
		QN1117-1.8V 0 ≤ I <sub>out</sub> ≤ 800mA, V <sub>in</sub> =3.8V	1.764	1.8	1.836	V
		QN1117 -2.5V 0 ≤ I <sub>out</sub> ≤ 800mA, V <sub>in</sub> =4.5V	2.45	2.5	2.55	V
		QN1117 -2.85V 0 ≤ I <sub>out</sub> ≤ 800mA, V <sub>in</sub> =4.85V	2.793	2.85	2.907	V
		QN1117 -3.3V 0 ≤ I <sub>out</sub> ≤ 800mA, V <sub>in</sub> =5.3V	3.234	3.3	3.366	V
		QN1117 -5.0V 0 ≤ I <sub>out</sub> ≤ 800mA, V <sub>in</sub> =7.0V	4.9	5	5.1	V

ΔV <sub>out</sub>	Line regulation	QN1117 -1.2V I <sub>out</sub> =10mA, 2.7V ≤ V <sub>in</sub> ≤ 10V		0.03	0.2	%/V
		QN1117 -ADJ I <sub>out</sub> =10mA, 2.75V ≤ V <sub>in</sub> ≤ 12V		0.03	0.2	%/V
		QN1117 -1.8V I <sub>out</sub> =10mA, 3.3V ≤ V <sub>in</sub> ≤ 12V		0.03	0.2	%/V
		QN1117 -2.5V I <sub>out</sub> =10mA, 4.0V ≤ V <sub>in</sub> ≤ 12V		0.03	0.2	%/V
		QN1117 -2.85V I <sub>out</sub> =10mA, 4.35V ≤ V <sub>in</sub> ≤ 12V		0.03	0.2	%/V
		QN1117 -3.3V I <sub>out</sub> =10mA, 4.8V ≤ V <sub>in</sub> ≤ 12V		0.03	0.2	%/V
		QN1117 -5.0V I <sub>out</sub> =10mA, 6.5V ≤ V <sub>in</sub> ≤ 12V		0.03	0.2	%/V

		QN1117 -1.2V V <sub>in</sub> =2.7V, 10mA ≤ I <sub>out</sub> ≤ 800mA		2	8	mV
		QN1117 -ADJ V <sub>in</sub> =2.75V, 10mA ≤ I <sub>out</sub> ≤ 800mA		2	8	mV
		QN1117 -1.8V V <sub>in</sub> =3.3V, 10mA ≤ I <sub>out</sub> ≤ 800mA		3	12	mV



# QN1117

## 800mA Bipolar Linear Regulator

$\Delta V_{out}$	Load regulation	QN1117 -2.5V $V_{in} = 4.0V, 10mA \leq I_{out} \leq 800mA$	4	16	mV
		QN1117 -2.85V $V_{in} = 4.35V, 10mA \leq I_{out} \leq 800mA$	5	20	mV
		QN1117 -3.3 $V_{in} = 4.8V, 10mA \leq I_{out} \leq 800mA$	6	24	mV
		QN1117 -5.0 $V_{in} = 6.5V, 10mA \leq I_{out} \leq 800mA$	9	36	mV
Vdrop	Dropout voltage	$I_{out} = 100mA$	1.2	1.3	V
		$I_{out} = 800mA$	1.3	1.5	V
Imin	Minimum load current	QN1117 -ADJ	2	10	mA
Iq	Quiescent Current	QN1117 -1.2V, $V_{in} = 10V$	2	5	mA
		QN1117 -1.8V, $V_{in} = 12V$	2	5	mA
		QN1117 -2.5V, $V_{in} = 12V$	2	5	mA
		QN1117 -2.85V, $V_{in} = 12V$	2	5	mA
		QN1117 -3.3V, $V_{in} = 12V$	2	5	mA
		QN1117 -5.0V, $V_{in} = 12V$	2	5	mA
IAdj	Adjust pin current	QN1117 -ADJ $V_{in} = 5V, 10mA \leq I_{out} \leq 800mA$	55	120	$\mu A$
Ichange	Iadj change	QN1117 -ADJ $V_{in} = 5V, 10mA \leq I_{out} \leq 800mA$	0.2	10	$\mu A$
OTP	Thermal Shutdown	Junction Temperature	+200		$^{\circ}C$
	Thermal Shutdown Hysteresis	Junction Temperature	+30		$^{\circ}C$
$\Delta V / \Delta T$	Temperature coefficient		$\pm 100$		ppm
$\theta_{JC}$	Thermal resistance	SOT-223	20		$^{\circ}C/W$
		TO-252	10		

Note1: All test are conducted under ambient temperature  $25^{\circ} C$  and within a short period of time 20ms

Note2: Load current smaller than minimum load current of QN1117-ADJ will lead to unstable or oscillation output.

### Detailed Description

QN1117 is a series of low dropout voltage, three terminal regulators. Its application circuit is very simple: the fixed version only needs two capacitors and the adjustable version only needs two resistors and two capacitors to work. It is composed of some modules including start-up circuit, bias circuit, bandgap, thermal shutdown, power transistors and its driver circuit and so on.

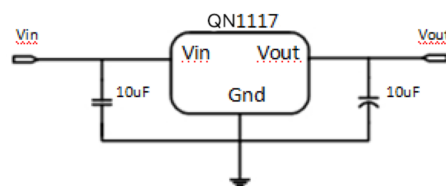
The thermal shut down modules can assure chip and its application system working safety when the junction temperature is larger than 140°C.

The bandgap module provides stable reference voltage, whose temperature coefficient is compensated by careful design considerations. The temperature coefficient is under 100 ppm/°C. And the accuracy of output voltage is guaranteed by trimming technique.

### Typical Application

QN1117 has an adjustable version and six fixed versions (1.2V, 1.8V, 2.5V, 2.85V , 3.3V and 5V)

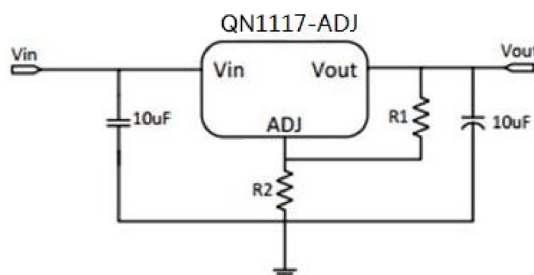
#### Fixed Output Voltage Version



Application circuit of QN1117 fixed version

- 1) Recommend using 10µF tan capacitor as bypass capacitor (C1) for all application circuit.
- 2) Recommend using 10µF tan capacitor to assure circuit stability.

#### Adjustable Output Voltage Version



Application Circuit of QN1117 -ADJ

The output voltage of adjustable version follows the equation:  $V_{out} = 1.25 \times (1 + R2/R1) + I_{Adj} \times R2$ . We can ignore  $I_{Adj}$  because  $I_{Adj}$  (about 50µA) is much less than the current of  $R1$  (about 2~10mA).

1) To meet the minimum load current (>10mA) requirement,  $R1$  is recommended to be 125ohm or lower. As QN1117-ADJ can keep itself stable at load current about 2mA,  $R1$  is not allowed to be higher than 625ohm.

2) Using a bypass capacitor ( $C_{ADJ}$ ) between the ADJ pin and ground can improve ripple rejection. This bypass capacitor prevents ripple from being amplified as the output voltage is increased. The impedance of  $C_{ADJ}$  should be less than  $R1$  to prevent ripple from being amplified. As  $R1$  is normally in the range of 100Ω~500Ω, the value of  $C_{ADJ}$  should satisfy this equation:  $1/(2 \pi \times f_{ripple} \times C_{ADJ}) < R1$ .

### Thermal Considerations

We have to take heat dissipation into great consideration when output current or differential voltage of input and output voltage is large. Because in such cases, the power dissipation consumed by QN1117 is very large.

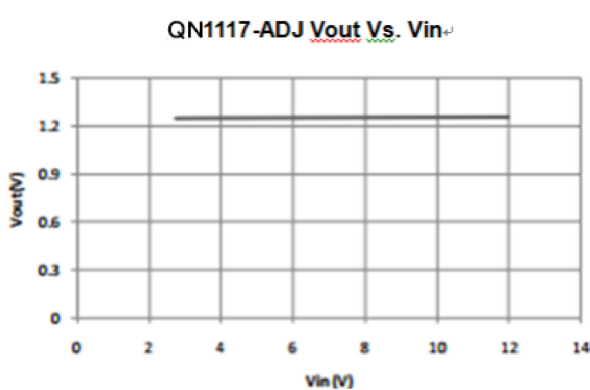
QN1117C series uses SOT-223 package type and its thermal resistance is about 20°C/W. And the copper area of application board can affect the total thermal resistance. If copper area is 5cm\*5cm (two sides), the resistance is about 30°C/W. So the total

thermal resistance is about 20°C/W + 30°C/W. We can decrease total thermal resistance by increasing copper area in application board. When there is no good heat dissipation copper are in PCB, the total thermal resistance will be as high as 120°C/W, then the power dissipation of QN1117C could allow on itself is less than 1W. And furthermore, QN1117C will work at junction temperature higher than 125°C under such condition and no lifetime is guaranteed.

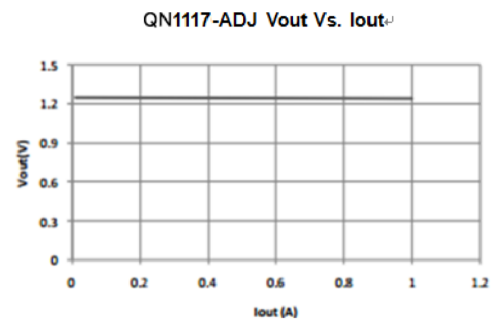
### Typical Performance Characteristics

T<sub>A</sub>=25°C, unless otherwise noted.

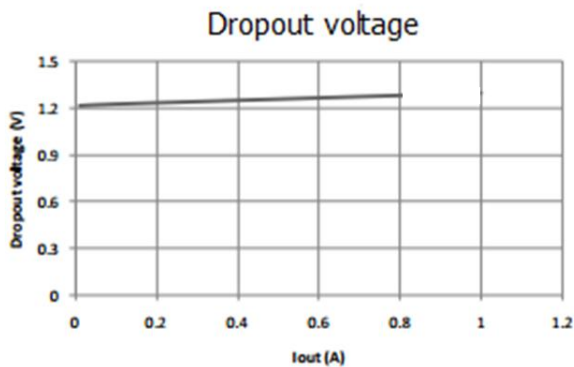
#### Line regulation



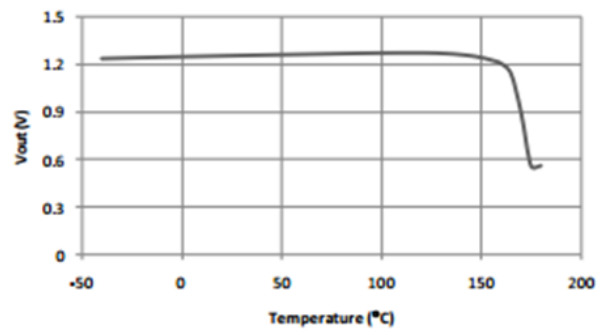
#### Load regulation



#### Dropout voltage

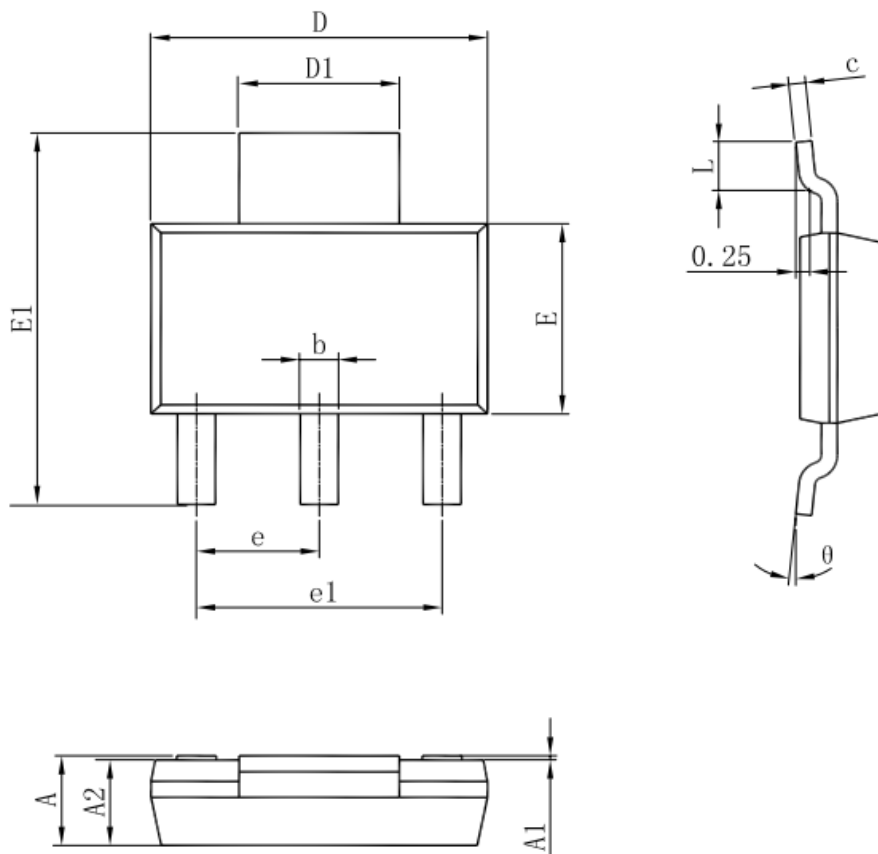


#### Thermal performance with OTP



**Package Information**

**SOT-223 PACKAGE OUTLINE DIMENSIONS**





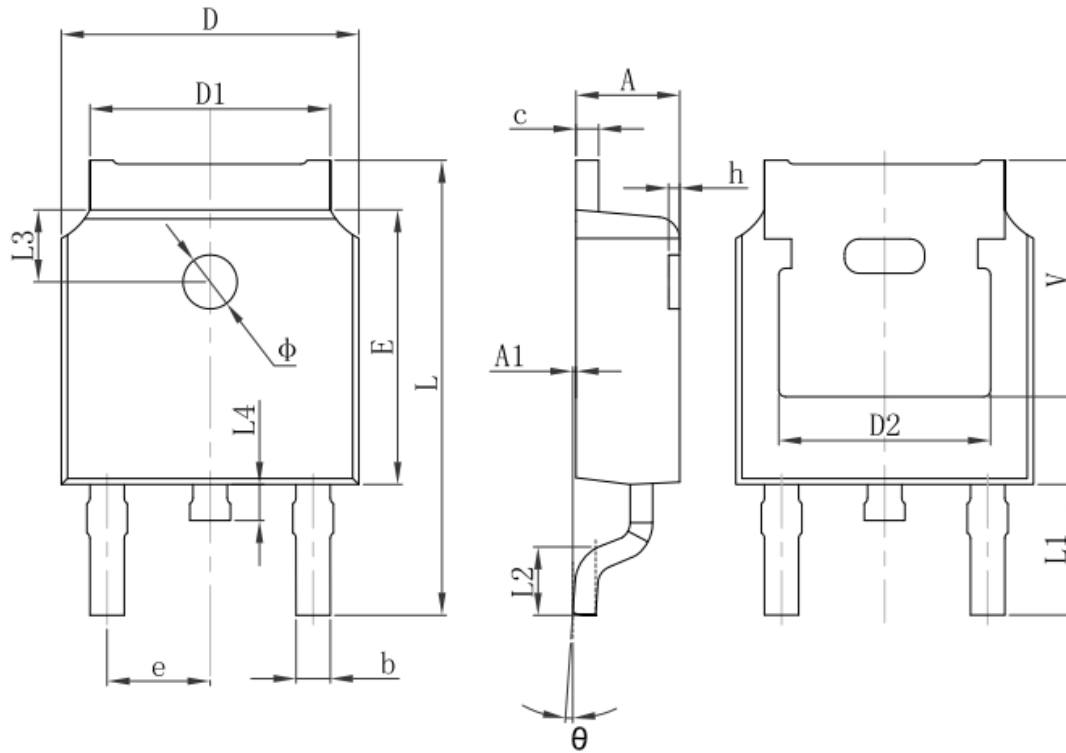


# QN1117

## 800mA Bipolar Linear Regulator

Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	1.520	1.800	0.060	0.071
A1	0.000	0.100	0.000	0.004
A2	1.500	1.700	0.059	0.067
b	0.660	0.820	0.026	0.032
c	0.250	0.350	0.010	0.014
D	6.200	6.400	0.244	0.252
D1	2.900	3.100	0.114	0.122
E	3.300	3.700	0.130	0.146
E1	6.830	7.070	0.269	0.278
e	2.300(BSC)		0.091(BSC)	
e1	4.500	4.700	0.177	0.185
L	0.900	1.150	0.035	0.045
θ	0°	10°	0°	10°

### TO-252-2L PACKAGE OUTLINE DIMENSIONS



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	2.200	2.400	0.087	0.094
A1	0.000	0.127	0.000	0.005
b	0.660	0.860	0.026	0.034
c	0.460	0.580	0.018	0.023
D	6.500	6.700	0.256	0.264
D1	5.100	5.460	0.201	0.215
D2	4.830 REF.		0.190 REF.	
E	6.000	6.200	0.236	0.244
e	2.186	2.386	0.086	0.094
L	9.800	10.400	0.386	0.409
L1	2.900 REF.		0.114 REF.	
L2	1.400	1.700	0.055	0.067
L3	1.600 REF.		0.063 REF.	
L4	0.600	1.000	0.024	0.039
$\phi$	1.100	1.300	0.043	0.051
$\theta$	0°	8°	0°	8°
h	0.000	0.300	0.000	0.012
V	5.350 REF.		0.211 REF.	